

# SEMICONDUCTOR TECHNICAL DATA

# SMFB13L

SCHOTTKY BARRIER TYPE DIODE

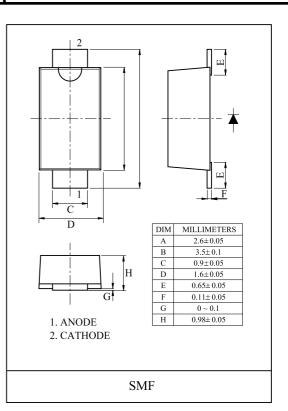
### SWITCHING TYPE POWER SUPPLY APPLICATIONS.

#### FEATURES

- · Low Profile Surface Mount Package.
- $\cdot$  Low Power Loss, High Efficiency.
- For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

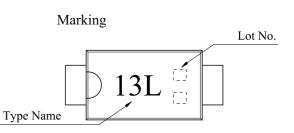
#### APPLICATION

- Switching Power Supply.
- · Reversed Battery Connection Protection.
- DC/DC Converter.
- · Cellular Phones.



## MAXIMUM RATING (Ta=25)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	30	V
Average Output Rectitifed Current	I <sub>O</sub>	1	А
Peak One Cycle Surge Forward Current (Non-Repetitive 60Hz)	I <sub>FSM</sub>	22	А
Junction Temperature	Tj	-40 125	
Storage Temperature Range	T <sub>stg</sub>	-40 125	

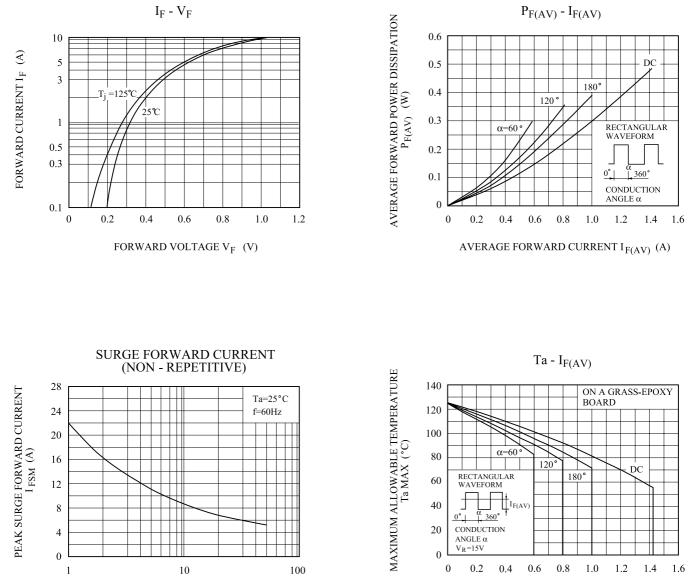


## ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V <sub>FM</sub>	I <sub>FM</sub> =1.0A	-	-	0.36	V
Repetitive Peak Reverse Current I <sub>RI</sub>	T	V <sub>RRM</sub> =20V	-	-	0.7	mA
	I <sub>RRM</sub>	V <sub>RRM</sub> =Rated	-	-	1.0	mA
Thermal Resistance	R <sub>th(j-1)</sub>	Junction to lead	-	-	1.0	
	R <sub>th(j-a)</sub>	Junction to ambient (on a grass-epoxy board)	-	-	140	/W



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NUMBER OF CYCLES

AVERAGE FORWARD CURRENT  $I_{F(AV)}$  (A)